

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S47	2	"20060097266"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/14 14:07
S48	1	"20060097266" and plate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/14 14:07
S49	67	(sic or silicon near2 carbide) near10 increas \$5 near2 diameter	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/19 23:18
S50	38	(sic or silicon near2 carbide) near10 increas \$5 near2 diameter and (sic or silicon near2 carbide) near10 (wafer or single near2 crystal \$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/19 23:19
S51	48	(sic or silicon near2 carbide) near10 deposit \$5 near4 around	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/19 23:23
S52	37	(shigehiro near2 nishino or kazutoshi near2 murata).in. and (sic or silicon near2 carbide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/19 23:32
S53	2941	(ring or annular\$6) near10 (sic or silicon near2 carbide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/19 23:33
S54	65	(ring or annular\$6) near10 (sic or silicon near2 carbide) near10 (vapor near2 deposit \$5 or cvd)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/19 23:33

S55	100	(sic or silicon near2 carbide) near15 single near2 crystal\$6 near15 deposit\$6 near16 polycrystal\$7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/19 23:34
S56	135	("alpha." or alpha or "6h") near10 (sic or silicon near2 carbide) near2 (wafer or substrate) same (beta or ".beta." or "3c") near15 (sic or silicon near2 carbide) near6 (film or layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/19 23:34

11/20/08 10:47:20 AM  
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